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(12) United States Patent

Tavkhelidze et al.

(54) SURFACE PAIRS

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- (60) Provisional application No. 60/149,805, filed on Aug. 18, 1999, provisional application No. 60/373,508, filed on Apr. 17, 2002, provisional application No. 60/366,563, filed on Mar. 22, 2002, provisional application No. 60/366,564, filed on Mar. 22, 2002.

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(57) ABSTRACT

The present invention is a method for fabricating an electrode pair precursor which comprises the steps of creating on one surface of a substrate one or more indents of a depth less than approximately 10 nm and a width less than approximately 1 µm; depositing a layer of material on the top of this structured substrate to forming a first electrode precursor; depositing another layer the first electrode precursor to form a second electrode precursor; and finally forming a third layer on top of the second electrode precursor.

13 Claims, 4 Drawing Sheets



